NSN 5961-01-209-3265



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-209-3265 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 2.000 inches **Overall Diameter:** 0.355 inches **End Application:** 1430-01-092-5948 patriot **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -80.0 collector to base voltage/static/emitter open and -80.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** -1.00 amperes source cutoff current

Power Rating Per Characteristic:

0.8 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: pnp

Test Data Document:

18876-11457019 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 insulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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